## Certificate IATF 0501329

## Certificate CN21/10214.04

The management system of

IATF USI: 353G6R

2nd Floor, No.1 Plant, No.98, Fenghuang Road, Economic and Technological Development Zone, Chizhou City, Anhui

Province, P. R. China

has been assessed and certified as meeting the requirements of

Edition 1

For the following Scope
Design and Manufacturing of Semiconductor discrete device diode TVS Chip.

## None

3 Year certification is valid from 20 February 2024 until 19 February 2027 and remains valid subject to satisfactory surveillance audits. Version no. 3. Current version updated 20 February 2024

Authorised by

Luck Yu

Veto Power Authority

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Luck GU





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